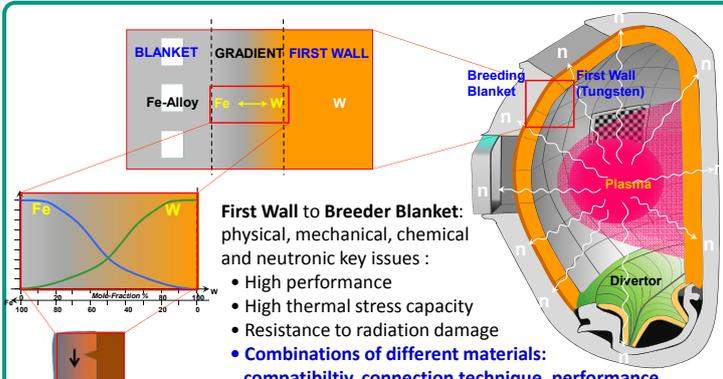


# Advanced Electrochemical Machining (ECM) for Tungsten Surface Micro-Structuring in Blanket Applications

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## Motivation



**BLANKET** GRADIENT **FIRST WALL**

Fe-Alloy  $\text{Fe} \rightarrow \text{W}$  W

Breeding Blanket First Wall (Tungsten) Plasma Divertor

**First Wall to Breeder Blanket:** physical, mechanical, chemical and neutronic key issues:

- High performance
- High thermal stress capacity
- Resistance to radiation damage
- **Combinations of different materials: compatibility, connection technique, performance**

**Need of adhesion promoters**

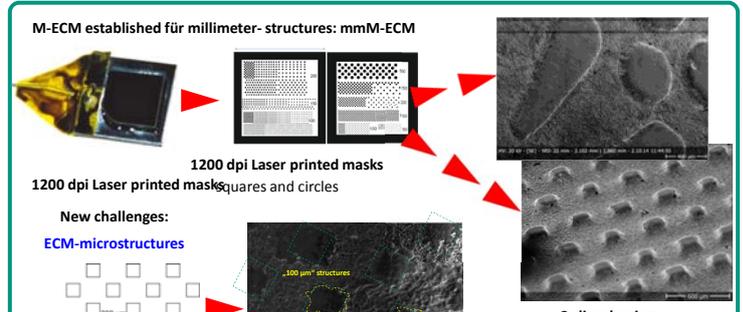
⇒ **Tungsten ↔ RAFM-Steels:** Force-fit and stable, but not to be affected by W-Fe mismatches. => **gradient material**: Vacuum plasma spraying

Microstructured devices (cubic, spheric, pyramidal) on First Wall backside to enable suitable **indentation** of  $W_{\text{bulk}} \leftrightarrow W_{\text{FGM}}$  to obtain **multifold increase of adhesion area.**

**Manufacturing ? => Electrochemical Machining !** ECM allows defectless shaping by metal dissolution (no thermal and mechanical stresses)

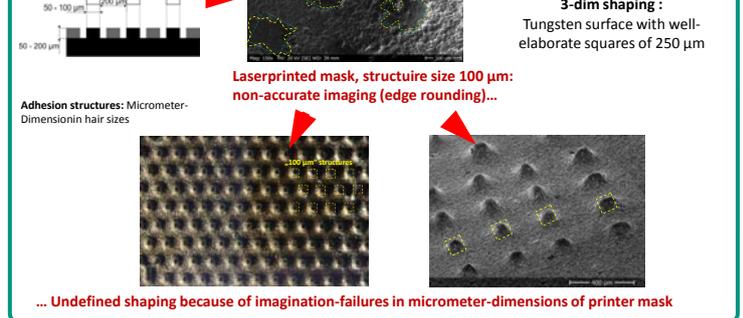
## Shaping of millimeter structures: mmM-ECM

M-ECM established für millimeter-structures: mmM-ECM



1200 dpi Laser printed masks  
1200 dpi Laser printed masks squares and circles

**New challenges:**  
ECM-microstructures



Laserprinted mask, structure size 100 µm: non-accurate imaging (edge rounding)...

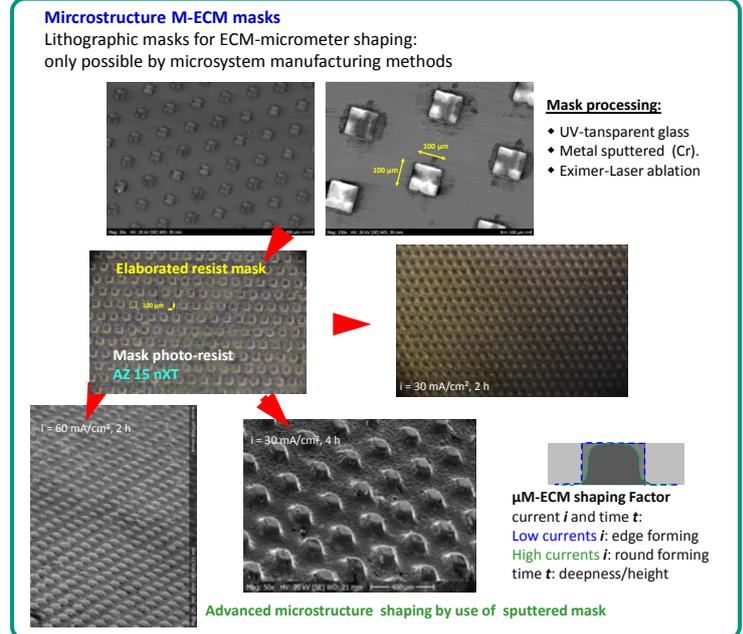
Adhesion structures: Micrometer-Dimension in hair sizes

... Undefined shaping because of imprecision-failures in micrometer-dimensions of printer mask

## Minaturization into Microstructures: µM-ECM

**Microstructure M-ECM masks**

Lithographic masks for ECM-micrometer shaping: only possible by microsystem manufacturing methods



**Mask processing:**

- UV-transparent glass
- Metal sputtered (Cr)
- Eximer-Laser ablation

Elaborated resist mask  
Mask photo-resist AZ 15 nXT

$i = 60 \text{ mA/cm}^2, 2 \text{ h}$

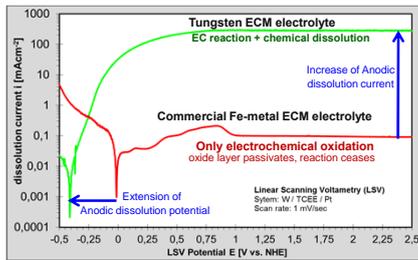
$i = 30 \text{ mA/cm}^2, 4 \text{ h}$

**µM-ECM shaping Factor** current  $i$  and time  $t$ :  
Low currents  $i$ : edge forming  
High currents  $i$ : round forming  
time  $t$ : deepness/height

Advanced microstructure shaping by use of sputtered mask

## Electrochemistry of tungsten

**Electro-chemical investigation:** tungsten dissolves in aqueous ECM electrolytes under formation of hydroxides, condensing to insulating oxides, ... but which are sensitive to variation of chemical environment (pH, nucleophiles,...)



Regular aqueous ECM electrolytes (for Iron metals) are **not suitable** for tungsten.

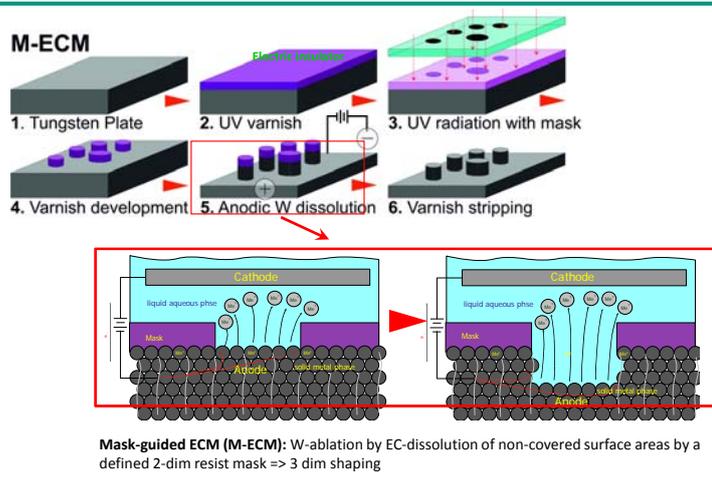
Developed W-ECM solution increases Anodic reaction over several decades.

**Effective and constant W-metal removal can take place in ECM if adopted e+c-reaction type by**

- two-component electrolyte
- electric pulse profiles

## ElectroChemical Machining (ECM) processes

**M-ECM**



1. Tungsten Plate
2. UV varnish
3. UV radiation with mask
4. Varnish development
5. Anodic W dissolution
6. Varnish stripping

**Mask-guided ECM (M-ECM):** W-ablation by EC-dissolution of non-covered surface areas by a defined 2-dim resist mask => 3 dim shaping

## Conclusion

The results of our investigations show that M-ECM can be developed into microstructure dimensions

- Standard two component electrolyte (TCEE) was used and conditions adopted to µm shaping
- W surfaces in strongly different geometrical features were successfully elaborated by specifically adapted suitable parameters
- High frequency pulse currents of  $10^3 \text{ Hz}$  are essential accuracy especially in C-ECM.
- 1<sup>st</sup> Milestone: Squares of 100 µm in required geometry imaged into tungsten bulk.
- Further investigations: structure size 50 µm, required edge rounding

## Acknowledgment

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